OMRON MOS FET Relays

Slim, 2.1-mm High Relay Incorporating a MOS FET Optically Coupled with an Infrared LED in a Miniature, Flat SOP Package

- Upgraded G3VM-S2 Series.
- Continuous load current of 110 mA.
- Dielectric strength of 1,500 Vrms between I/O.

■ Application Examples

- Broadband systems
- Measurement devices
- Data loggers
- Amusement machines

■ List of Models



G3VM-351G

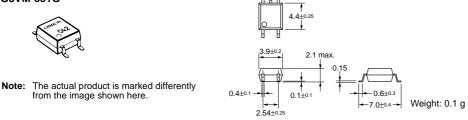
Note: The actual product is marked differently from the image shown here.

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	350 VAC	G3VM-351G	100	
terminals			G3VM-351G(TR)		2,500

Dimensions

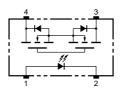
Note: All units are in millimeters unless otherwise indicated.

G3VM-351G



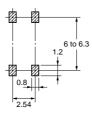
■ Terminal Arrangement/Internal Connections (Top View)

G3VM-351G



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

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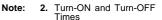


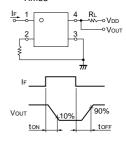
■ Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Rating	Unit	Measurement Conditions		
Input	nput LED forward current		50	mA			
Repetitive peak LED forward current		I _{FP}	1	A	100 μs pulses, 100 pps		
	LED forward current reduction rate	$\Delta I_{F}^{\circ}C$	-0.5	mA/°C	$Ta \geq 25^\circ C$		
	LED reverse voltage	V _R	5	V			
	Connection temperature	Тј	125	°C			
Output	Output dielectric strength	V _{OFF}	350	V			
	Continuous load current	I _O	110	mA			
	ON current reduction rate	$\Delta I_{ON} / ^{\circ}C$	-1.1	mA/°C	$Ta \geq 25^\circ C$		
	Connection temperature	Тj	125	°C			
	Dielectric strength between input and output (See note 1.)		1,500	Vrms	AC for 1 min		
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation		
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation		
Soldering temperature (10 s)			260	°C	10 s		

■ Electrical Characteristics (Ta = 25°C)

	ltem	Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA	
	Reverse current	I _R			10	μA	V _R = 5 V	
	Capacity between terminals	CT		30		pF	V = 0, f = 1 MHz	
	Trigger LED forward current	I _{FT}		1	3	mA	I _O = 100 mA	
Output	Maximum resistance with output ON	R _{ON}		25	35	Ω	I _F = 5 mA, I _O = 110 mA, t < 1 s	
				35	50	Ω	I _F = 5 mA, I _O = 110 mA	
	Current leakage when the relay is open	I _{LEAK}			1.0	μΑ	V _{OFF} = 350 V	
Capacity between I/O terminals		C _{I-O}		0.8		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance		R _{I-O}	1,000			MΩ	$\label{eq:VIOC} \begin{array}{l} V_{I\text{-O}} = 500 \ \text{VDC}, \\ \text{RoH} \leq 60\% \end{array}$	
Turn-ON time		tON		0.3	1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega, V_{DD} = 20 \text{ V} (\text{See note 2.})$	
Turn-OFF time		tOFF		0.1	1.0	ms		





Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

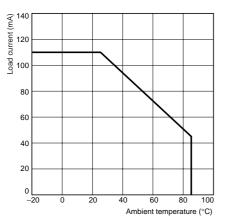
Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			280	V
Operating LED forward current	I _F	5	7.5	25	mA
Continuous load current	lo			100	mA
Operating temperature	T _a	- 20		65	°C

Engineering Data

Load Current vs. Ambient Temperature G3VM-351G

■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.



Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

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Datasheets for electronic components.